

IN THE SPECIFICATION

Please amend the specification at page 1, lines 3-8, as follows:

**Cross Reference to Related Applications**

This application is related to an application by Luk et al., entitled 3T1D MEMORY CELLS USING GATED DIODES AND METHODS OF USE THEREOF, U.S. Patent Serial No. ~~XX/XXX,XXX~~ 10/751,713, filed on the same day as the present application and assigned to International Business Machines, Inc., the disclosure of which is hereby incorporated by reference.